# Spin tunneling properties in $m$ esoscopic $m$ agnets: e ects of a m agnetic eld 

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#### Abstract

The tunneling of a giant spin at excited levels is studied theoretically in $m$ esoscopic $m$ agnets $w$ ith a $m$ agnetic eld at an arbitrary angle in the easy plane. D i erent structures of the tunneling barriers can be generated by the $m$ agnetocrystalline anisotropy, the $m$ agnitude and the orientation of the eld. By calculating the nonvacuum instanton solution explicitly, we obtain the tunnel splittings and the tunneling rates for di erent angle ranges of the extemalm agnetic eld $\left({ }_{\mathrm{H}}=2\right.$ and $=2<{ }_{\mathrm{H}}<$ ). The temperature dependences of the decay rates are clearly show $n$ for each case. It is found that the tunneling rate and the crossover tem perature depend on the orientation of the extemalm agnetic eld. This feature can be tested with the use of existing experim ental techniques.

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## I. IN TRODUCTION

Recently, nanospin system s have em erged as good candidates to display quantum phenom ena at a $m$ esoscopic orm acrosoopic scalen' tum tunneling was possible in ferrom agnetic (FM) nanoparticles containing as much as $10^{5} \quad 10^{6}$ spins $\stackrel{n_{1}^{\prime \prime}}{n^{\prime}}$ At extrem ely low tem perature, the $m$ agnitude of the totalm agnetization $M$ is frozen out and thereby its direction becom es the only dynam ical variable. In the absence of an extemal $m$ agnetic eld, the $m$ agnetocrystalline anisotropy can create energetically degenerate easy directions depending on the crystal sym $m$ etry. Tunneling betw een neighboring states rem oves the degeneracy of the original ground states and leads to a level splitting. This phenomenon is called macroscopic quantum coherence ( $\mathrm{M} Q \mathrm{C}$ ). H ow ever, MQC is hard to be observed in experim ents w ithout controlling the height and the width of the barrier. It has been believed that a magnetic eld is a good extemal param eter to $m$ ake the quantum tunneling observable. By applying a m agnetic eld in a properdirection, one of the two energetically equivalent orientations becom es $m$ etastable and the $m$ agnetization vector can escape from the $m$ etastable state through the barrier to a stable one, which is called $m$ acroscopic quantum tunneling ( $M Q T$ ). A large num ber of experim ents involving resonance $m$ easurem ents, $m$ agnetic relaxation, and hysteresis loop study, $M$ ossbauer spectroscopy, and neutron scattering study for various system s show ed either tem peratureindependent relaxation phenom ena or a well-de ned resonance depending exponentially on the num ber of total spins, which supported the idea ofm agnetic quantum tunneling ${ }^{\left[\eta^{\prime \prime}\right.}$

To our know ledge, the tunneling of a single spin degree of freedom was rst studied by K orenblit and Shender in 1978 ${ }^{2 \cdot \overline{2} 1} \mathrm{M}$ ore recently, the tunneling problem of the m agnetization reversal was studied extensively for the single-dom ain FM nanoparticles in a m agnetic eld applied at an arbitrary angle. This problem was studied by Zaslavskii with the help of $m$ apping the spin system onto a one-dim ensional particle system ${ }^{3}$ in For the sam e system, $M$ igueland C hudnovsky $y^{\text {nin }^{\prime \prime}}$ calculated the tunneling rate by applying the im aginary-tim e path integral, and dem onstrated that the angular and eld dependences of the tunneling exponent
obtained by Zaslavskii's $m$ ethod and by the path-integral m ethod coincide precisely. K im and Hwang perform ed a calculation based on the instanton technique for FM particles $w$ ith biaxial and tetragonal crystal sym $m$ etry ${ }^{\prime}{ }^{5}$ ', and K im extended the tunneling rate for biaxial crystal sym $m$ etry to a nite tem perature 'a' The quantum -classical transition of the escape rate for uniaxial spin system in an arbitrarily directed eld was investigated by $G$ aranin, $H$ idalgo and Chudnovsky w th the help of $m$ apping onto a particle $m$ oving in a double-well potentialn ${ }^{[\quad 1}$ The sw itching eld $m$ easurem ent was carried out on single-dom ain FM nanoparticles of Barium ferrite ( BaFeC oT io) containing about $10^{5} \quad 1 \delta^{\circ}$ spins. $T$ he $m$ easured angular dependance of the crossover tem perature was found to be in excellent agreem ent w ith the theoretical prediction "'A'" which strongly suggests the quantum tunneling ofm agnetization in the BaFeC oT io nanoparticles. Lu et al studied the quantum tunneling of the $N$ eel vector in single-dom ain antiferrom agnetic (AFM) nanoparticles with biaxial, tetragonal, and hexagonal crystal sym $m$ etry in an arbitrarily directed eld ${ }^{\text {'? }}$

It is noted that the previous results of spin tunneling at excited levels in an arbitrarily directed eld were obtained by num erically solving the equation of m otion satis ed by the least tra jectory' ${ }^{\prime \prime}$ and the system considered in Ref. 6 had the sim ple biaxial crystal sym $m$ etry. The purpose of this paper is to present an analytical study of the quantum tunneling at excited levels in the FM particles w ith an arbitrarily directed eld. M oreover, the system considered in this paper has a much more com plex structure (i. e., the general structure in experim ents), such as trigonal, tetragonal, and hexagonal crystal sym m etry. By applying an arbitrarily directed $m$ agnetic eld, the problem does not possess any sym $m$ etry and for that reason is $m$ ore di cult $m$ athem atically. H ow ever, it is worth pursuing because of its signi cance for experim ents and the easiest to im plem ent in practice. Since the result of spin tunneling at excited levels for tetragonal sym $m$ etry is a generalization of that of tunneling at ground-state levels studied by K im and H wang ${ }^{\prime \prime \prime}$ theirs by taking the low-energy lim it. Wewill show that MQC and MQT can be consecutively observed by changing the direction ofm agnetic eld, and discuss their dependence on the direction and the $m$ agnitude of eld. The dependence of the crossover tem perature
$T_{c}$ and the $m$ agnetic viscosity (which is the inverse of W KB exponent at the quantum -tunneling-dom inated regin e $T \quad T_{c}$ ) on the direction and the $m$ agnitude of the eld, and the $m$ agnetic anisotropies is expected to be observed in fiuture experim ents on individual single-dom ain particles w ith di erent $m$ agnetocrystalline anisotropies. B oth the nonvacuum (or them al) instanton orbounce solution, the W K B exponents and the preexponential factors are evaluated exactly for di erent angle ranges of the magnetic eld ( $\mathrm{H}==2$ and $=2<\boldsymbol{н}<\quad$. The low -energy lim it of our results agrees well with that of ground-state spin tunneling. In order to com pare theories w ith experim ents, predictions of the crossover tem perature corresponding to the transition from classical to quantum behavior and the tem perature dependence of the decay rate are clearly shown in this paper. B oth variables are expressed as a function of param eters which can be changed experim entally, such as the number of total spins, the e ective anisotropy constants, the strength and orientation of applied $m$ agnetic eld. O ur results show that the distinct angular dependence, together with the dependence of the W KB tunneling rate on the strength of the extemalm agnetic eld, $m$ ay provide an independent experim ental test for the spin tunneling at excited levels in nanoscale $m$ agnets. $W$ hen the ective $m$ agnetic anisotropy of the particle is know $n$, our theoretical results give clear predictions with no tting param eters. Therefore, quantum spin tunneling could be studied as a function of the e ective magnetic anisotropy. Our results should be helpfiul for future experim ents on spin tunneling in single-dom ain particles w ith di erent m agnetocrystalline anisotropies.

This paper is structured in the follow ing way. In Sec. II, we review brie y som e basic ideas of spin tunneling in FM particles. A nd we discuss the fundam entals conceming the com putation of level splittings and tunneling rates of excited states in the doublewell-like potential. In Secs. III, IV, and V, we study the spin tunneling at excited levels for FM particles w ith trigonal, tetragonal and hexagonal crystal sym m etry in an extemalm agnetic eld applied in the ZX plane with a range of angles $=2 \mathrm{H}_{\mathrm{H}}<$, respectively. The conclusions are presented in Sec. V I.
II. PHYSICALMODELOFSPIN TUNNELING IN FM PARTICLES

For a spin tunneling problem, the tunnel splltting or the tunneling rate is determ ined by the im aginary-tim e transition amplitude from an initialstate $\ddot{\mu}$ ito a nalstate fí as

$$
U_{f i}=h f j e^{H T} \nexists i={ }^{Z} D \quad \exp \left(S_{E}\right) ;
$$

where $S_{E}$ is the Euclidean action and $D$ is the $m$ easure of the path integral. In the spin-coherent-state representation, the Euclidean action is

$$
\begin{equation*}
S_{E}(;)=\frac{V}{\sim}^{Z} d \quad i \frac{M_{0}}{d} \frac{d}{d} \quad \stackrel{M_{0}}{i} \frac{d}{d} \cos +E(;) ; \tag{2}
\end{equation*}
$$

where $V$ is the volum e of the FM particle and is the gyrom agnetic ratio. $M_{0}=\mathrm{M}_{\mathrm{M}} \mathrm{j}=$ $\sim S=V$, where $S$ is the total spin of FM particles. It is noted that the rst two term $S$ in Eq. (2) de ne the Berry phase or $W$ ess-Zum ino, Chem-Sin ons term whid arises from the nonorthogonality of spin coherent states in the north-pole param etrization. The W essZum ino term has a sim ple topological intenpretation. For a closed path, this term equals
iS tim es the area swept out on the unit sphere between the path and the north pole. The
rst term in Eq. (2) is a totalim aginary-tim e derivative, which has no e ect on the classical equations ofm otion, but it is crucial for the spin-parity e ects ind instanton or bounce trajectory described in this paper (as show $n$ in the follow ing), this tim $e$ derivative gives a zero contribution to the path integral, and therefore can be om itted.

In the sem iclassical lim it, the dom inant contribution to the transition am plitude com es from nite action solution (instanton or bounce) of the classical equation of $m$ otion. The instanton's contribution to the tunneling rate or the tunnel splitting is given by ${ }_{\mathrm{L}}^{\mathrm{I}}$ "

$$
\begin{equation*}
\text { (or } \quad \text { ) }=A!p{\frac{S_{c l}}{2}}^{1=2} e^{S_{c l}} \text {; } \tag{3}
\end{equation*}
$$

where $!p$ is the oscillation frequency in the well, $S_{C l}$ is the classical action, and the prefactor A originates from the quantum uctuations about the classical path. It is noted that Eq. (3) is based on quantum tunneling at the level of ground state, and the tem perature dependence of the tunneling rate (ie., tunneling at excited levels) is not taken into account.

H ow ever, the instanton technique is suitable only for the evaluation of the tunneling rate or the tunnel splltting at the vacuum level, since the usual (vacuum ) instantons satisfy the vacuum boundary conditions. In this paper, we will calculate the nonvacuum instantons corresponding to quantum tunneling at excited levels.

For a particle moving in a double-well-like potential $(x)$, the level spllttings of degenerate excited levels or the im aginary parts of the m etastable levels at an energy E > 0 are given by the follow ing form ula in the W KB approxim ation ${ }^{\circ} \mathrm{H}$. ${ }^{\circ}$

$$
\begin{equation*}
E \quad(\text { or } \operatorname{Im} E)=\frac{!(E)}{} \exp [S(E)] ; \tag{4}
\end{equation*}
$$

and the im aginary-tim e action is

$$
\begin{equation*}
S(E)=2^{p} \overline{2 m}_{x_{x_{1}(E)}^{x_{2}(E)}}^{d x} \mathrm{P}^{\mathrm{U}(\mathrm{X}) \quad \mathrm{E}} \text {; } \tag{5}
\end{equation*}
$$

$w$ here $\mathrm{x}_{1 ; 2}(E)$ are the tuming points for the particle oscillating inside the inverted potential
$U(x) .!(E)=2=t(E)$ is the energy-dependent frequency, and $t(E)$ is the period of the real-tim e oscillation in the potential well,

$$
\begin{equation*}
t(E)=p \frac{1 m}{2 m}_{Z_{x_{3}(E)}^{x_{4}(E)}}^{P} \frac{d x}{E \operatorname{U}(x)} ; \tag{6}
\end{equation*}
$$

where $x_{3 ; 4}(E)$ are the tuming points for the particle oscillating inside the potential $U(x)$.

## III. M Q C AND M Q T FOR TRIGONALCRYSTAL SYMMETRY

In this section, we study the quantum tunneling of the $m$ agnetization vector in singledom ain FM nanoparticles with trigonal crystal sym $m$ etry. The extemal magnetic eld is applied in the ZX plane, at an angle in the range of $=2$ н $<$. N ow the total energy E ( ; ) can be written as

$$
\begin{equation*}
E(;)=K_{1} \sin ^{2} \quad K_{2} \sin ^{3} \quad \cos (3) \quad M_{0} H_{x} \sin \quad \cos \quad M_{0} H_{z} \cos +E_{0} ; \tag{7}
\end{equation*}
$$

where $K_{1}$ and $K_{2}$ are the $m$ agnetic anisotropy constants satisfying $K_{1} \quad K_{2}>0$, and $E_{0}$ is a constant which m akes $\mathrm{E}(\mathrm{i})$ zero at the initial orientation. As the magnetic eld is
applied in the ZX plane, $H_{x}=H \sin H_{H}$ and $H_{z}=H \operatorname{Cos}{ }_{H}$, where $H$ is the $m$ agnitude of the eld and ${ }_{H}$ is the angle between the $m$ agnetic eld and the $b$ axis.

By introducing the dim ensionless param eters as

$$
\begin{equation*}
\overline{\mathrm{K}}_{2}=\mathrm{K}_{2}=2 \mathrm{~K}_{1} ; \overline{\mathrm{H}}_{\mathrm{x}}=\mathrm{H}_{\mathrm{x}}=\mathrm{H}_{0} ; \overline{\mathrm{H}}_{\mathrm{z}}=\mathrm{H}_{\mathrm{z}}=\mathrm{H}_{0} ; \tag{8}
\end{equation*}
$$

Eq. (7) can be rew ritten as

$$
\begin{equation*}
\bar{E}(;)=\frac{1}{2} \sin ^{2} \quad \bar{K}_{2} \sin ^{3} \quad \cos (3) \quad \bar{H}_{x} \sin \quad \cos \quad \bar{H}_{z} \cos +\bar{E}_{0} ; \tag{9}
\end{equation*}
$$

where $\mathrm{E}(;)=2 \mathrm{~K}_{1} \overline{\mathrm{E}}(;)$, and $\mathrm{H}_{0}=2 \mathrm{~K}_{1}=\mathrm{M}_{0}$. At nite m agnetic eld, the plane given by $=0$ is the easy plane, on which $\overline{\mathrm{E}}(\mathrm{i})$ reduces to

$$
\begin{equation*}
\overline{\mathrm{E}}(;=0)=\frac{1}{2} \sin ^{2} \quad \bar{K}_{2} \sin ^{3} \quad \overline{\mathrm{H}} \cos (\quad \text { н })+\overline{\mathrm{E}}_{0}: \tag{10}
\end{equation*}
$$

W e denote o to be the initial angle and c the critical angle at which the energy barrier vanishes when the extemalm agnetic eld is close to the critical value $\overline{\mathrm{H}}_{\mathrm{C}}\left({ }_{\mathrm{H}}\right)$ (to be calculated in the following). Then, the initial angle osatis es $d \bar{E}(;=0)=\mathrm{d}=0=0$, the critical angle $c_{c}$ and the dim ensionless critical eld $\bar{H}_{c}$ satisfy both $d \bar{E}(;=0)=\mathrm{d}={ }_{c} ; \bar{H}=\bar{H}_{c}=0$ and $d^{2} \overline{\mathrm{E}}(; \quad=0)=d^{2}={ }_{c ;} \bar{H}_{=} \bar{H}_{c}=0$. A fter som e algebra, $\bar{H}_{c}\left({ }_{\mathrm{H}}\right)$ and $c$ are found to be 2

$+6 \overline{\mathrm{~K}}_{2} \frac{1}{1+\text { jot н J }^{2=3}}{ }^{3=2} 5$;

N ow we consider the lim iting case that the extemalm agnetic eld is slightly low er than the critical eld, i.e., $=1 \overline{\mathrm{H}} \overline{=}_{\mathrm{C}} \quad$ 1. At this practically interesting situation, the barrier height is low and the width is narrow, and therefore the tunneling rate in $M Q T$ or the tunnel splitting in M Q C is large. Introducing co(j j 1 in the lim it of 1), expanding
$\mathrm{dE}(;=0)=\mathrm{d}=0=0$ about ${ }_{\mathrm{c}}$, and using the relations $\mathrm{d} \overline{\mathrm{E}}(;=0)=\mathrm{d} \quad={ }_{c} ; \overline{\mathrm{H}}=\overline{H_{c}}=$ 0 and $d^{2} \bar{E}(;=0)=d^{2}={ }_{c} \bar{H}=\bar{H}_{c}=0$, we obtain the approxim ation equation for in the order of ${ }^{3=2}$,

$$
\begin{align*}
& \bar{H}_{c} \sin \left(\begin{array}{c}
\text { с }
\end{array}\right) \quad 2 \frac{3}{4} \sin 2_{c}+3 \bar{K}_{2} \cos 3 \mathrm{c} \\
& +\quad \bar{H}_{c} \cos \left(\begin{array}{c}
\text { н }
\end{array}\right)+2 \frac{1}{2} \cos 2_{c} \quad \bar{K}_{2} \sin 3 \mathrm{c}=0: \tag{12}
\end{align*}
$$

Then $\overline{\mathrm{E}}(;)$ reduces to the follow ing equation in the lim it of sm all,

$$
\begin{equation*}
\overline{\mathrm{E}}(;)=2 \overline{\mathrm{~K}}_{2} \sin ^{2}(3=2) \sin ^{3}(0+)+\overline{\mathrm{H}}_{\mathrm{x}} \sin (0+)(1 \cos )+\overline{\mathrm{E}}_{1}() ; \tag{13}
\end{equation*}
$$

where
o(j j 1 in the lim it of $\quad 1$ ), and $\bar{E}_{1}()$ is a function of only given by
$\frac{1}{2} \bar{H}_{c} \cos \left(\begin{array}{c}\text { н }\end{array}\right) \quad \overline{3 K}_{2} \sin ^{3}$ с $4 \sin c_{c} \cos ^{2}$ с $\quad 2 \quad \frac{3}{2}{ }^{2}+3 \frac{1}{4}_{4}$
$\frac{3}{2} \bar{K}_{2} \sin ^{3}$ c $4 \sin { }_{c} \cos ^{2} c^{2}$ :

In the follow ing, we w ill investigate the tunneling behaviors of the $m$ agnetization vector at excited levels in FM particles w th trigonal crystal sym m etry at di erent angle ranges of the extemalm agnetic eld as ${ }_{\mathrm{H}}=2$ and $=2<_{\mathrm{H}}<$, respectively.

$$
\text { A. } H_{H}=2
$$

For ${ }_{H}=2$, we have ${ }_{c}==2$ from Eq. (11b) and $={ }^{\mathrm{P}} \overline{2}^{2}+\frac{9}{2} \bar{K}_{2}$ from Eq. (12). Eqs (13) and (14) show that is very small for the full range of angles $=2 \quad{ }_{\mathrm{H}}<$. Perform ing the Gaussian integration over, we can $m$ ap the spin system onto a particle moving problem in the one-dim ensional potential well. $N$ ow the im aginary-tim e transition am plitude Eqs. (1) and (2) becom es

$$
\begin{aligned}
& \text { Z }
\end{aligned}
$$

w ith the e ective $m$ ass

$$
\mathrm{m}=\frac{\sim S^{2}}{2 \mathrm{VK}_{1} 1+{\overline{9 K_{2}}}^{1}} ;
$$

and the e ective potential

$$
\begin{equation*}
U()=\frac{K_{1} V}{4 \sim}{ }^{2}(2\}: \tag{16}
\end{equation*}
$$

Theplot of the e ective potential $\bar{E}_{1}()$ as a function of $(=\quad 0)$ for ${ }_{H}=2$ is shown in Fig .1 , and $\sim \mathrm{U}()=2 \mathrm{~K}_{1} V \bar{E}_{1}()$. The problem is one of $\mathrm{M} Q \mathrm{C}$, where the $m$ agnetization vector resonates coherently betw een the energetically degenerate easy directions at $=0$ and $=2^{\mathrm{P}} \overline{2} 1+\frac{9}{2} \overline{\mathrm{~K}}_{2}$ separated by a classically im penetrable barrier at $\quad={ }^{\mathrm{P}} \overline{2}_{1}+\frac{9}{2} \overline{\mathrm{~K}}_{2}$.

The nonvacuum (or therm al) instanton con guration pwhich minim izes the Euclidean action in Eq. (16) satis es the equation ofm otion

$$
\begin{equation*}
\frac{1}{2} m{\frac{d_{p}}{d}}^{2} \quad U(p)=E ; \tag{17}
\end{equation*}
$$

where $\mathrm{E}>0$ is a constant of integration, which can be view ed as the classicalenergy of the pseudoparticle con guration. Then the kink-solution is

$$
\begin{equation*}
p=+p \overline{2}^{2} \operatorname{sn}\left(!_{1} ; k\right) ; \tag{18}
\end{equation*}
$$

where $=2 \underset{\frac{\mathrm{q}}{\frac{\sim \mathrm{E}}{}}}{\mathrm{K}_{1} \mathrm{~V}}$, and $!_{1}=\mathrm{q}_{\frac{\mathrm{K}_{1} \mathrm{~V}}{2 \sim \mathrm{~m}}} \mathrm{p} \overline{2+} . \operatorname{sn}\left(!_{1} \quad ; \mathrm{k}\right)$ is the Jacobian elliptic sine function of $m$ odulus $k=\frac{\frac{2}{2}}{2^{2}}$. The Euclidean action of the nonvacuum instanton con guration Eq. (18) over the dom ain ( ; ) is found to be

$$
\begin{equation*}
S_{p}={ }^{Z} \quad \mathrm{~d} \quad \frac{1}{2} \mathrm{~m} \frac{\mathrm{~d}_{\mathrm{p}}}{\mathrm{~d}}{ }^{2}+\mathrm{U}(\mathrm{p})=\mathrm{W}+2 \mathrm{E} ; \tag{19a}
\end{equation*}
$$

w ith
where $k^{@}=1 \quad k^{2}$, and $=1=k_{B} T$ with $k_{B}$ the Boltzm ann constant. $K(k)$ and $E(k)$ are the com plete elliptic integral of the rst and second kind, respectively. The general form ula

Eq. (4) gives the tunnel spllttings of excited levels as $E=\frac{!(E)}{} \exp (W)$, where $W$ is shown in Eq. (19b), and ! $(E)=\frac{2}{t(E)}$ is the energy-dependent frequency. For this case, the period $t(\mathbb{E})$ is found to be

$$
\begin{equation*}
t(E)=p \frac{Z}{2 m} \int_{1}^{2} p \frac{d}{E \quad U()}=2 \frac{r}{\frac{2 \sim m}{K_{1} V}} p \frac{1}{2^{2}+} K \quad\left(k^{0}\right) ; \tag{20}
\end{equation*}
$$

where ${ }_{1}=+\mathrm{P} \overline{2}$, and ${ }_{2}=\quad+\frac{\mathrm{P}}{{ }^{2}+}$. N ow we discuss the low energy lim it where $E$ is $m u c h$ less than the barrier height. In this case, $k^{04}=\frac{16 \sim \mathrm{E}}{\mathrm{K}_{1} \mathrm{~V}^{4}} \quad 1$, so we can perform the expansions of $K(k)$ and $E(k)$ in Eq. (19b) to include term $s l i k e k^{04}$ and $k^{04} \ln \frac{4}{k^{0}}$,

$$
\begin{aligned}
& \mathrm{E}(\mathrm{k})=1+\frac{1}{2} \ln \frac{4}{\mathrm{k}^{0}} \quad \frac{1}{2} \mathrm{k}^{@}+\frac{3}{16} \ln \frac{4}{\mathrm{k}^{0}} \quad \frac{13}{12} \mathrm{k}^{\infty 4} \\
& \mathrm{~K}(\mathrm{k})=\ln \frac{4}{\mathrm{k}^{0}}+\frac{1}{4} \ln \frac{4}{\mathrm{k}^{0}} \quad 1 \mathrm{k}^{@}+\frac{9}{64} \ln \frac{4}{\mathrm{k}^{0}} \quad \frac{7}{6} \mathrm{k}^{\infty 4}
\end{aligned}
$$

;

W ith the help ofsm all oscillator approxim ation for energy near the bottom of the potential well, $E_{n}=n+\frac{1}{2} \quad{ }_{1}, \quad 1=\frac{q}{\frac{1}{m} U^{\infty}(=0)}=\frac{q}{\frac{2 K}{}{ }^{2} V}$, Eq. (19b) is expanded as

$$
\begin{equation*}
\mathrm{W}=\mathrm{W}_{0} \quad \mathrm{n}+\frac{1}{2}+\mathrm{n}+\frac{1}{2} \ln \frac{1 \quad \overline{2} \frac{15}{2} \overline{\mathrm{~K}}_{2}}{2^{9=2} \mathrm{~S} \mathrm{~S}^{3=2}} \mathrm{n}+\frac{1}{2} \quad \text {; } \tag{21a}
\end{equation*}
$$

where

$$
\begin{equation*}
\mathrm{W}_{0}=\frac{2^{5=2}}{3} \mathrm{~S}^{3=2} \quad 1+\frac{1}{2}+\frac{15}{2} \overline{\mathrm{~K}}_{2} \quad: \tag{21b}
\end{equation*}
$$

Then the low-lying energy shift of $n$-th excited states for FM particles $w$ ith trigonal crystal sym $m$ etry in the presence of an extemal $m$ agnetic eld applied perpendicular to the anisotropy axis ( $\mathrm{H}^{=}=2$ ) is

$$
\begin{equation*}
\sim E_{n}=\frac{2}{\mathrm{P}!}\left(K_{1} V\right)^{1=2} S^{1} \quad 1 \quad \overline{2}+\frac{21}{2} \bar{K}_{2} \quad \frac{2^{9=2} S^{3=2}}{1 \overline{\overline{2}}^{\frac{15}{2} \bar{K}_{2}}}{ }_{n+1=2} \exp \left(W_{0}\right): \tag{22}
\end{equation*}
$$

For $\mathrm{n}=0$, the energy shift of the ground state is

$$
\sim E_{0}=\frac{2^{13=4}}{P-}\left(K_{1} V\right)^{5=4} S^{1=2} \quad 1 \quad-+\frac{57}{4} \bar{K}_{2} \quad \exp \left(W_{0}\right):
$$

Then Eq. (22) can be w ritten as

$$
\begin{equation*}
\sim E_{n}=\frac{q_{1}^{n}}{n!}\left(\sim E_{0}\right) ; \tag{24a}
\end{equation*}
$$

where

$$
\begin{equation*}
q_{1}=\frac{2^{9=2} S^{3=2}}{1 \quad \overline{2} \quad \frac{15}{2} \bar{K}_{2}}: \tag{24b}
\end{equation*}
$$

Since we have obtained the tunnel splittings at excited levels, it is reasonable to study the tem perature dependence of the tunneling rate. It is noted that Eqs. (24a) and (24b) are obtained under the condition that the levels in the two wells are degenerate. In $m$ ore general cases, the transition am plitude betw een two levels separated by the barrier or the decay rate should be sensitive to this resonance condition for the two levels. If in the case of the potentialw ith tw o degenerate levels only one of the levels is considered as a perturbative $m$ etastable state; how ever, a ctitious im aginary energy can be calculated by consideration of possible back and forth tunneling (ie., by regarding the instanton-antiinstanton pair as a bounce-like con guration) in the barrier. Therefore there exists a relation between the level splitting and this im aginary part ofm etastable energy level, and has been referred to as the B ogom olny $\mp$ ateyev relation based on equilibrium therm odynam ics ${ }^{5}$ ?

$$
\begin{equation*}
\operatorname{Im} E_{n}=\left(E_{n}\right)^{2}=4!\left(E_{n}\right) ; \tag{25}
\end{equation*}
$$

where ! $\left(E_{n}\right)$ is the frequency of oscillations at energy level $E_{n}$. At nite tem perature $T$ the decay rate $=2 \mathrm{Im} \mathrm{E}_{\mathrm{n}}$ can be easily found by averaging over the Boltzm ann distribution

$$
\begin{equation*}
(T)={\frac{2}{Z_{0}}}_{n}^{X} \operatorname{Im} E_{n} \exp \left(\sim E_{n}\right) ; \tag{26}
\end{equation*}
$$

$w$ here $Z_{0}={ }^{P}{ }_{n} \exp \left(\sim E_{n}\right)$ is the partition function $w$ ith the harm onic oscillator approxin ated eigenvalues $\mathrm{E}_{\mathrm{n}}=\mathrm{n}+\frac{1}{2} \quad 1$. W ith the help of the B ogom olny $\mp$ ateyev relation Eq. (25), the nal result of the tunneling rate at a nite tem perature $T$ is found to be

$$
\begin{equation*}
(T)=\frac{1}{2_{1}} 1 \quad e^{\sim} \quad(E \quad)^{2} I_{0} 2 q_{I} e^{\sim}{ }_{1}^{=2} ; \tag{27}
\end{equation*}
$$

where $E_{0}$ and $q_{1}$ are shown in Eqs. (23) and (24b). $I_{0}(x)={ }^{P}{ }_{n=0}(x=2)^{2 n}=(n!)^{2}$ is the m odi ed Bessel function.

Now we discuss brie $y$ the dissipation e ect on spin tunneling. For a spin tunneling problem, it is im portant to consider the discrete level structure. It was quantitatively show n that the phenom enon of M Q C depends crucially on the width of the excited levels in the right wellisi Including the ects of dissipation, the decay rate, in particular, is given by

$$
\begin{equation*}
\mathrm{n}=\frac{1}{2}\left(\mathrm{E}_{\mathrm{n}}\right)^{2} \mathrm{X}_{\mathrm{n}^{0}} \frac{\mathrm{nn}^{0}}{\left(\mathrm{E}_{\mathrm{n}} \quad \mathrm{E}_{\mathrm{n} 0}\right)^{2}+{\underset{\mathrm{nn}}{ }}_{2}^{2}} ; \tag{28}
\end{equation*}
$$

where $E_{n}$ is the level splitting, $n^{0}$ are the levels in the other well and $n n^{0}$ is the sum of the linew idths of the $n$th and $n^{0}$ th levels caused by the coupling of the system to the environm ent. For the exact resonance conditions, the tem perature dependence of the decay rate is

$$
\begin{equation*}
(T)=X_{n}^{X} \frac{\left(E_{n}\right)^{2}}{2} \exp \left(\sim E_{n}\right) ; \tag{29}
\end{equation*}
$$

where the level broadening $n$ contains all the details of the coupling between the $m$ agnet and its environm ent. If the width caused by the dissipative coupling su ciently large, the levels overlap, so that the problem is $m$ ore or less equivalent to the tunneling into the structureless continuum. In this case, the results obtained in this paper should be changed by including the dissipation. It is noted that the purpose of this paper is to study the spin tunneling at excited levels for single-dom ain FM particles in $m$ agnetic eld at su ciently low tem peratures. Strong dissipation is hardly the case for single-dom ain m agnetic particles ${ }^{2}{ }^{2} 1$ and thereby our results are expected to hold. It has been argued that the decay rate should oscillate on the applied $m$ agnetic eld depending on the relative $m$ agnitude between the width and the level spacing should be the e ect of nite tem perature in the problem of spin tunneling. T he fullanalysis of spin tunneling onto the precession levels rem ains an open problem .

$$
\text { В. }=2<{ }_{\mathrm{H}}<
$$

For $=2<{ }_{H}<$, the critical angle $c$ is in the range of $0<{ }_{c}<=2$, and $p \overline{2=3}$. By applying the sim ilar $m$ ethod, the problem can be $m$ apped onto a problem of
one-dim ensionalm otion by integrating out, and for this case the e ective $m$ ass $m$ and the e ective potentialu ( ) in Eq. (15) are found to be
and $U()=3 U_{0} q^{2} \quad 1 \quad \frac{2}{3} q$, w ith $q=3=2 \overline{6} \overline{6}$, and

The dependence of the e ective potential $\bar{E}_{1}()$ on $(=\quad 0)$ for ${ }_{H}=3=4$ is plotted in $F$ ig. 2, and $\sim U()=2 \mathrm{~K}_{1} V \mathrm{E}_{1}()$. The problem now becom es one of $\mathrm{M} Q \mathrm{~T}$, where the $m$ agnetization vector escapes from the $m$ etastable state at $=0$ through the barrier by quantum tunneling.

The nonvacuum bounce con guration with an energy E $>0$ is found to be

$$
\begin{equation*}
p=\frac{2}{3} \overline{6} \quad a \quad(a \quad b) \operatorname{sn}^{2}(!2 ; k) ; \tag{31}
\end{equation*}
$$

where

$$
\begin{equation*}
!_{2}=\frac{1}{2} \overline{\frac{3 U_{0}}{2 m}} \mathrm{p} \overline{\mathrm{a}} \mathrm{C} \tag{32}
\end{equation*}
$$

$\mathrm{a}(\mathbb{E})>\mathrm{b}(\mathbb{E})>\mathrm{c}(\mathbb{E})$ denote three roots of the cubic equation

$$
\begin{equation*}
q^{3} \quad \frac{3}{2} q^{2}+\frac{E}{2 U_{0}}=0: \tag{33}
\end{equation*}
$$

$\operatorname{sn}\left(!_{2} ; k\right)$ is the Jacobian elliptic sine function ofm odulus $k=\frac{q}{\frac{a b}{a c}}$.
The classical action of the nonvacuum bounce con guration Eq. (31) is

$$
\begin{equation*}
S_{p}=\mathrm{Z}^{\text {" }} \quad \mathrm{d} \frac{1}{2} m{\frac{d_{p}}{d}}^{2}+U\left({ }_{p}\right)=W+2 E ; \tag{34a}
\end{equation*}
$$

w ith

$$
\begin{equation*}
\mathrm{W}=\frac{2^{9=2}}{5 \quad \beta^{=2}} \bar{m} \mathrm{U}_{0}(\mathrm{a} \quad \mathrm{C})^{5=2} 2 \mathrm{k}^{4} \quad \mathrm{k}^{2}+1 \mathrm{E}(\mathrm{k}) \quad 1 \quad \mathrm{k}^{2} \quad 2 \quad \mathrm{k}^{2} \mathrm{~K}(\mathrm{k}): \tag{34b}
\end{equation*}
$$

The period $t(E)$ of this case is found to be
where $k^{\mathbb{L}}=1 \quad k^{2}$. Then the general form ula Eq. (4) gives the im aginary parts of the $m$ etastable energy levels as $\operatorname{Im} E=\frac{!(E)}{} \exp (W)$, where ! $(E)=\frac{2}{t(E)}$, and $W$ is shown in Eq. (34b).

Here we discuss the low energy lim it of the im aginary part of the $m$ etastable energy
 b $\quad \frac{3}{4} k^{@} \quad 1+\frac{3}{4} k^{@}, \mathrm{c} \quad \frac{3}{4} k^{@} 1+\frac{1}{4} k^{@}$, and $k^{@ 4}=\frac{16 \mathrm{E}}{27 \mathrm{U}_{0}} \quad$ 1. A fter some calculations, we obtain the im aginary part of the low-lying metastable excited levels as $\sim \operatorname{Im} \mathrm{E}_{\mathrm{n}}=\frac{\mathrm{q}_{\mathrm{n}}}{\mathrm{n}!}\left(\sim \operatorname{Im} \mathrm{E}_{0}\right)$, where

The im aginary part of the m etastable ground-state level is

$$
\begin{align*}
& \frac{1}{8} \bar{K}_{2} \frac{512 \text { jot }_{H} \mathrm{~J}^{2=3}}{1+\text { jot }_{\mathrm{H}}^{2=3} \mathrm{~J}^{1=2}}+\frac{1}{2} \bar{K}_{2} \frac{3+\text { jot }_{H} \mathrm{~J}^{2=3}}{1+\text { jot }_{\mathrm{H}} \mathrm{~J}^{2=3}}{ }^{3=2} 5 \exp \left(\mathrm{~W}_{0}\right): \tag{37a}
\end{align*}
$$

where the W KB exponent is

$$
\begin{align*}
& \mathrm{W}_{0}=\frac{2^{17=4} \mathrm{j}^{1=4}}{5} \mathrm{~S}^{5=4} \text { jot }{ }_{\mathrm{H}} \mathrm{~J}^{1=6} 1+\frac{\overline{2}}{2} \frac{9}{2} \overline{\mathrm{~K}}_{2} 1+\text { jot }_{\text {н }} \mathrm{J}^{2=3}{ }^{1=2} \\
& +\frac{1}{4} \bar{K}_{2} \frac{2+9 \text { jot }_{H} \mathrm{~J}^{2=3}}{1+\text { jot }_{\text {H J }} \mathrm{J}^{1=3}} \overline{\mathrm{~K}}_{2} \frac{3+\text { jot }_{\text {H }} \mathrm{J}^{2=3}}{1+\text { jot }_{\mathrm{H}} \mathrm{~J}^{2=3}} 7^{3=2} 5: \tag{37b}
\end{align*}
$$

$T$ he decay rate at a nite tem perature $T$ is found to be

$$
\begin{equation*}
(\mathrm{T})=2 \mathrm{Im} \mathrm{E}_{0} 1 \quad \mathrm{e}^{\sim}{ }^{2} \exp \mathrm{q}_{\mathrm{L}} \mathrm{e}^{\sim}{ }^{2}: \tag{38}
\end{equation*}
$$

In $F$ ig. 3 we plot the tem perature dependence of the tunneling rate for the typical values of param eters for nanom eter-scale single-dom ain ferrom agnets: $\mathrm{S}=6000,=1 \overline{\mathrm{H}}=\bar{H}_{\mathrm{C}}=$ $0: 01 ; \bar{K}_{2}=0: 01$, and ${ }_{H}=3=4$. From Fig. 3 one can easily see the crossover from purely quantum tunneling to therm ally assisted quantum tunneling. The tem perature $\mathrm{T}_{0}{ }^{(0)}$ characterizing the crossover from quantum to therm al regim es can be estim ated as $\mathrm{k}_{\mathrm{B}} \mathrm{T}_{0}{ }^{(0)}=$ $\mathrm{U}=\mathrm{W} 0$, where U is the barrier height, and W 0 is the W KB exponent of the ground-state tunneling. It can be shown that in the cubic potential ( $q^{2} q^{3}$ ), the usual second-order phase transition from the therm al to the quantum regim es occurs as the tem perature is low ered. The second-order phase transition tem perature is given by $k_{B} T_{0}^{(2)}=\frac{\sim!}{2}$, where $!_{b}=\frac{q}{\frac{1}{m} j J^{\infty}\left(x_{b}\right) j}$ is the frequency of $s m$ all oscillations near the bottom of the inverted potential $U(x)$, and $x_{0}$ corresponds to the bottom of the inverted potential. For the present case, it is easy to obtain that

$$
\begin{aligned}
& \frac{1}{4} \bar{K}_{2} \frac{212 \text { jot }_{H} \mathrm{~J}^{2=3}}{1+\text { jot }_{\mathrm{H} \mathrm{~J}^{2=3}}^{1=2}}+\overline{\mathrm{K}}_{2} \frac{3+\text { jot }_{\mathrm{H}} \mathrm{~J}^{2=3}}{1+\text { jot }_{\mathrm{H}}^{2=3} \mathrm{~J}^{3=2}} \mathrm{~F}^{7} ;
\end{aligned}
$$

and $\mathrm{k}_{\mathrm{B}} \mathrm{T}_{0}^{(0)}=(5=18) \mathrm{k}_{\mathrm{B}} \mathrm{T}_{0}^{(2)} \quad 0: 87 \mathrm{k}_{\mathrm{B}} \mathrm{T}_{0}^{(2)}$. For a nanom eter-scale single-dom ain FM particle, the typical values of param eters for the $m$ agnetic anisotropy coe cients are $K_{1}=10^{8}$ erg $/ \mathrm{cm}^{3}$, and $K_{2}=10^{5} \mathrm{erg} / \mathrm{cm}^{3}$. The radius of the $F M$ particle is about 12 nm and the sublattioe spin is $10^{6}$. In Fig. 4, we plot the ${ }_{\mathrm{h}}$ dependence of the crossover tem perature $T_{C}$ for typical values of param eters for nanom eter-scale ferrom agnets at $=0: 001$ in a wide range of angles $=2<{ }_{\mathrm{H}}<$. Fig. 4 show sthat the $m$ axim al value of $\mathrm{T}_{\mathrm{C}}$ is about 026 K at ${ }_{\mathrm{H}}=1: 76$. Them axim al value of $\mathrm{T}_{\mathrm{C}}$ as well as is expected to be observed in experim ent. If $=0: 001$, we obtain that $T_{c}(135) v 023 \mathrm{~K}$ corresponding to the crossover from quantum to classical regim e. N ote that, even for as sm all as $10^{3}$, the angle corresponding to an appreciable change of the orientation of the $m$ agnetization vector by quantum tunneling is ${ }_{2}={ }^{\mathrm{P}} \overline{6}$ rad> 4. It is quite large enough to distinguish easily betw een the two states for experim ental tests.

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IV.MQC AND MQT FOR TETRAGONALCRYSTAL SYM M ETRY
```

In this section, we study the FM particles w ith tetragonal crystal sym m etry in a magnetic eld at arbitrarily directed angles in the ZX plane, which has the m agnetocrystalline anisotropy energy

$$
\begin{equation*}
E(;)=K_{1} \sin ^{2}+K_{2} \sin ^{4} \quad K_{2}^{0} \sin ^{4} \quad \cos (4) \quad M_{0} H_{x} \sin \quad \cos \quad M_{0} H_{z} \cos +E_{0} ; \tag{39}
\end{equation*}
$$

$w$ here $K_{1}, K_{2}$ and $K_{2}^{0}$ are the $m$ agnetic anisotropy coe cients, and $K_{1}>0$. In the absence ofm agnetic eld, the easy axes of this system are bfor $K_{1}>0$. A nd the eld is applied in the ZX plane as in the previous section. By using the dim ensionless param eters de ned in Eq. (8), and choosing $K_{2}^{0}>0$, we nd that $=0$ is an easy plane for this system, at which Eq. (38) reduces to

$$
\begin{equation*}
\overline{\mathrm{E}}(;=0)=\frac{1}{2} \sin ^{2}+\overline{\mathrm{K}}_{2} \overline{\mathrm{~K}}_{2}^{0} \sin ^{4} \quad \overline{\mathrm{H}} \cos (\quad \text { н })+\overline{\mathrm{E}}_{0} ; \tag{40}
\end{equation*}
$$

where $\bar{K}_{2}^{0}=K_{2}^{0}=2 \mathrm{~K}_{1}$. A ssum ing that $\bar{K}_{2} \quad \overline{\mathrm{~K}}_{2}^{0} \quad 1$, we obtain the criticalm agnetic eld and the critical angle as

$$
\begin{align*}
& \sin _{c}=\frac{1}{1+\text { jot }_{H} \mathrm{~J}^{2=3}} 1+\frac{8}{3} \bar{K}_{2} \quad \bar{K}_{2}^{0} \frac{\text { jot }_{H} J^{2=3}}{1+\text { jot }_{H} J^{2=3}}: \tag{41}
\end{align*}
$$

Introducing $\quad 0$ (j j 1 in the sm all lim it), we derive the energy $\bar{E}(;)$ as

$$
\begin{equation*}
\overline{\mathrm{E}}(;)=\overline{\mathrm{K}}_{2}^{0}[1 \quad \cos (4)] \sin ^{4}(0+)+\overline{\mathrm{H}}_{\mathrm{x}}(1 \quad \cos ) \sin (0+)+\overline{\mathrm{E}}_{1}() ; \tag{42}
\end{equation*}
$$

where $\bar{E}_{1}()$ is a function of only given by

$$
\begin{align*}
& \bar{E}_{1}()=\frac{1}{2} \bar{H}_{c} \sin \left(\begin{array}{ll}
c & H
\end{array}\right)+\bar{K}_{2} \quad \bar{K}_{2}^{0} \sin \left(4 c_{c}\right) \quad 3 \quad 3^{2} \\
& +\frac{1}{8} \bar{H}_{c} \cos \left(\begin{array}{c}
\text { с }
\end{array}\right)+\bar{K}_{2} \bar{K}_{2}^{0} \cos \left(4{ }_{\mathrm{C}}\right) \quad 4 \quad 4^{3}+6^{2}{ }^{2} \quad 4^{2} \\
& +4 \overline{\mathrm{~K}}_{2} \quad \overline{\mathrm{~K}}_{2}^{0} \quad{ }^{2} \cos \left(4{ }_{\mathrm{c}}\right): \tag{43}
\end{align*}
$$

A. $h^{\prime}=2$
For this case, we obtain that $\quad \mathrm{P} \overline{2}^{h} 1 \quad 4 \overline{\mathrm{~K}}_{2} \quad \overline{\mathrm{~K}}_{2}^{0}{ }^{\mathrm{i}}$, and ${ }_{c}==2$. Perform ing the G aussian integration over, we can $m$ ap the spin system onto a problem of particle $w$ ith e ective $m$ ass $m m$ oving in the one-dim ensional potential well $U$ ( ). For this case,

$$
\mathrm{m}=\frac{\mathrm{h}}{2 \mathrm{VK}_{1} 1}+4 \mathrm{~S}^{2} \overline{\mathrm{~K}}_{2} \overline{\mathrm{~K}}_{2}^{0}+16 \overline{\mathrm{~K}}_{2}^{0}{ }^{i} ;
$$

and

$$
\begin{equation*}
\mathrm{U}()=\frac{\mathrm{K}_{1} \mathrm{~V}}{4 \sim} 1+12 \overline{\mathrm{~K}}_{2}{\overline{\mathrm{~K}}_{2}^{0}}^{\mathrm{i}}{ }^{2}(2\}: \tag{44}
\end{equation*}
$$

By applying the $m$ ethod sim ilar to that in Sec. III. A, we obtain the low-lying tunnel splltting at degenerate excited levels as $\sim E_{n}=\frac{9_{3}^{n}}{n!}\left(\sim E_{0}\right)$, where $\mathcal{G}_{3}=\frac{2^{9=2} S_{S}^{3=2}}{1 \overline{\bar{L}^{+}+8\left(\overline{K_{2}} \overline{K_{2}^{0}}\right)+8 \bar{K}_{2}^{0}}}$. The energy shift of the ground state is

$$
\begin{equation*}
\sim E_{0}=\stackrel{2^{13=4}}{P-\left(K_{1} V\right)^{5=4} S^{1=2} \quad 1 \quad-\quad+4 \bar{K}_{2} \quad \exp \left(\quad W_{0}\right): ~} \tag{45a}
\end{equation*}
$$

where the W KB exponent is

$$
\begin{equation*}
\mathrm{W}_{0}=\frac{2^{5=2}}{3} S^{3=2} 1+\frac{\mathrm{h}}{2} \quad 8 \overline{\mathrm{~K}}_{2} \quad \overline{\mathrm{~K}}_{2}^{0} \quad \overline{8 \mathrm{~K}}_{2}^{0}: \tag{45.b}
\end{equation*}
$$

Eqs. (45a) and (45b) agree well w ith the result obtained w ith the help of the vacuum instanton solution A nd the nal result of the decay rate at a nite tem perature $T$ is $(T)=\left(\begin{array}{lllll}E & )^{2} & 1 & e^{\sim}{ }^{3}=2 I_{0} 2 q_{G} e^{\sim}{ }^{3}=2 \text {, where } I_{0}(x) \text { is the modi ed Bessel }\end{array}\right.$ function.

$$
\begin{aligned}
& \text { B. }=2<{ }_{\mathrm{H}}< \\
& \text { For }=2<_{\boldsymbol{H}}<, \quad \mathrm{P} \overline{2=3} \text {, the e ective } \mathrm{m} \text { ass } \mathrm{m} \text { is }
\end{aligned}
$$

and the e ective potential is $\mathrm{U}\left(\mathrm{O}=3 \mathrm{U}_{0} \mathrm{q}^{2} \quad 1 \quad \frac{2}{3} \mathrm{q}\right.$, w ith $\mathrm{q}=3=2^{\mathrm{p}} \overline{6}$, and

For this case, the im aginary part of the low-lying $m$ etastable excited levels is $\sim \operatorname{Im} \mathrm{E}_{\mathrm{n}}=$
 ground-state level is

$$
\begin{align*}
& 1 \frac{-}{4}+4 \bar{K}_{2}^{0}+\frac{2}{3} \bar{K}_{2} \quad \overline{\mathrm{~K}}_{2}^{0} \frac{12 \text { jot }_{\mathrm{H}} \mathrm{~J}^{2=3}}{1+\text { jöt }_{\mathrm{H}} \mathrm{~J}^{2=3}} 7^{\mathrm{j}} \exp \left(\mathrm{~W}_{0}\right): \tag{47a}
\end{align*}
$$

where

The nal result of the decay rate at a nite temperature $T$ is (T) = $2 \mathrm{Im} \mathrm{E}_{0} 1 \mathrm{e}^{\sim}{ }^{4} \exp q_{4} \mathrm{e}^{\sim}{ }^{4}$. And the second-order phase transition tem perature characterizing the crossover from quantum to therm al regim es is found to be

$$
\begin{aligned}
& \mathrm{k}_{\mathrm{B}} \mathrm{~T}_{0}^{(2)}=\frac{2^{1=4} \quad \mathrm{j}^{2=4}}{\text { " }}\left(\mathrm{K}_{1} \mathrm{~V}\right) \text { S }^{1 \quad 1=4} \frac{\text { jot }_{\text {H }} \mathrm{j}^{\mathrm{l}=6}}{1+\text { joot }_{\text {H }} \mathrm{J}^{2=3}} \\
& 1 \quad \overline{2}+8 \overline{\mathrm{~K}}_{2}^{0}+\frac{4}{3} \overline{\mathrm{~K}}_{2} \overline{\mathrm{~K}}_{2}^{0} \frac{5 \text { jot }_{\mathrm{H} ~} \mathrm{~J}^{2=3}}{1+\text { jot }_{\mathrm{H} \mathrm{~J}}^{2=3}} \text { \# }
\end{aligned}
$$

## V.MQCAND MQTEOR HEXAGONALCRYSTALSYMMETRY

In this section, we study the hexagonal spin system whose m agnetocrystalline anisotropy energy $\mathrm{E}_{\mathrm{a}}(\mathrm{i})$ at zero m agnetic eld can be written as

$$
\begin{equation*}
E_{a}(;)=K_{1} \sin ^{2}+K_{2} \sin ^{4}+K_{3} \sin ^{6} \quad K_{3}^{0} \sin ^{6} \cos (6) ; \tag{48}
\end{equation*}
$$

where $K_{1}, K_{2}, K_{3}$, and $K_{3}^{0}$ are the $m$ agnetic anisotropic coe cients. The easy axes are $b$ for $K_{1}>0 . W$ hen we apply an extemalmagnetic eld at an arbitrarily directed angle in the Z X plane, the total energy of this system is given by

$$
\begin{equation*}
E(;)=E_{a}(;) \quad M_{0} H_{x} \sin \cos \quad M_{0} H_{z} \cos +E_{0} \text {; } \tag{49}
\end{equation*}
$$

By choosing $K_{3}^{0}>0$, we take $=0$ to be the easy plane, at which the potentialenergy can be written in term s of the dim ensionless param eters as

$$
\begin{equation*}
\overline{\mathrm{E}}(;=0)=\frac{1}{2} \sin ^{2}+\overline{\mathrm{K}}_{2} \sin ^{4}+\overline{\mathrm{K}}_{3} \overline{\mathrm{~K}}_{3}^{0} \sin ^{6} \quad \overline{\mathrm{H}} \cos (\quad \text { н })+\overline{\mathrm{E}}_{0} ; \tag{50}
\end{equation*}
$$

where $\bar{K}_{3}=K_{3}=2 \mathrm{~K}_{1}$ and $\overline{\mathrm{K}}_{3}^{0}=\mathrm{K}_{3}^{0}=2 \mathrm{~K}_{1}$.
U nder the assum ption that $\overline{\mathrm{K}}_{2}, \overline{\mathrm{~K}}_{3} \overline{\mathrm{~K}}_{3}^{0} \quad$ 1, we obtain the dim ensionless critical eld $\overline{\mathrm{H}}_{\mathrm{c}}$ and the critical angle c as

By introducing a sm all variable $\quad 0$ ( $j \mathrm{j} 1$ in the lim it of 1 ), the total energy becom es

$$
\begin{equation*}
\overline{\mathrm{E}}(;)=\overline{\mathrm{K}}_{3}^{0}[1 \quad \cos (6)] \sin ^{6}(0+)+\overline{\mathrm{H}}_{\mathrm{x}}(1 \quad \cos ) \sin (0+)+\overline{\mathrm{E}}_{1}() ; \tag{52}
\end{equation*}
$$

where $\bar{E}_{1}()$ is a function of only given by

$$
\begin{align*}
& 10 \sin ^{2}{ }^{c} \cos ^{2} c+5 \cos ^{4} c 4^{3}+6^{2}{ }^{2} 4^{2}+{ }^{2} 4 \bar{K}_{2} \cos \left(4{ }_{c}\right) \\
& +12 \overline{\mathrm{~K}}_{3} \overline{\mathrm{~K}}_{3}^{0} \sin ^{2}{ }_{\mathrm{c}} \sin ^{4}{ }^{\mathrm{c}} \quad 10 \sin ^{2}{ }_{\mathrm{c}} \cos ^{2}{ }_{\mathrm{c}}+5 \cos ^{4}{ }_{\mathrm{c}} \quad: \tag{53}
\end{align*}
$$

$$
\text { A. } \mathrm{H}==2
$$

For ${ }_{\mathrm{H}}=2$, i.e., the extemalm agnetic eld is applied penpendicular to the anisotropy axis, we obtain that $c==2$ and $=\bar{p}^{2} 1 \quad \overline{4 K}_{2} \quad 12 \bar{K}_{3} \quad \overline{\mathrm{~K}}_{3}^{0}$. . The spin system
can bem apped onto a particle w ith e ective $m$ assm $m$ oving in the one-dim ensionalpotential wellu ( ), where

$$
\begin{equation*}
\mathrm{m}=\frac{\mathrm{h}}{2 \mathrm{VK}_{1} 1} \quad \bar{\sim}^{2} \quad \mathrm{~S}^{2} \quad 6 \overline{\mathrm{~K}}_{3} \quad \overline{\mathrm{~K}}_{3}^{0} \quad 3 \overline{\mathrm{~K}}_{3}^{0}{ }^{i} ; \tag{54a}
\end{equation*}
$$

and

$$
\begin{equation*}
\mathrm{U}\left(\mathrm{)}={\frac{\mathrm{K}_{1} \mathrm{~V}}{\mathrm{~h}}}_{4 \sim} 1+12 \overline{\mathrm{~K}}_{2}+30 \overline{\mathrm{~K}}_{3}{\overline{\mathrm{~K}}_{3}^{0}}^{\mathrm{i}}{ }_{2}(2\}:\right. \tag{54b}
\end{equation*}
$$

By applying the sim ilar m ethod, we obtain that the energy shift of the $n$-th excited level is $\sim E_{n}=\frac{q_{n}^{n}}{n!}\left(\sim E_{0}\right)$, where

$$
q_{5}=\frac{2^{9=2} S^{3=2}}{1 \overline{\bar{L}}^{2}+8 \bar{K}_{2}+24 \bar{K}_{3} \bar{K}_{3}^{0}+18 \bar{K}_{3}^{0}}:
$$

The energy shift of the ground state is

$$
\begin{equation*}
\sim E_{0}=\frac{2^{13=4}}{P-}\left(K_{1} V\right)^{5=4} S^{1=2} 1 \quad \overline{4} \quad 6 \bar{K}_{3} \quad \bar{K}_{3}^{0}+9 \bar{K}_{3}^{0^{i}} \exp \left(W_{0}\right) ; \tag{55a}
\end{equation*}
$$

and the $W \mathrm{~KB}$ exponent is

$$
\begin{equation*}
\mathrm{W}_{0}=\frac{2^{5=2}}{3} S^{3=2} 1+\frac{\mathrm{h}}{2} \quad \overline{8 K}_{2} \quad 24 \overline{\mathrm{~K}}_{3} \quad \overline{\mathrm{~K}}_{3}^{0} \quad 1 \overline{\mathrm{~K}}_{3}^{0^{i}}: \tag{55b}
\end{equation*}
$$

$T$ he decay rate at a nite tem perature $T$ is

$$
(T)=\left(\begin{array}{llllllll}
E & 0
\end{array}\right)^{2} \quad 1 \quad e^{\sim} \quad=2 \quad 5 \quad I_{0} \quad 2 g_{5} e^{\sim}{ }^{5}=2 ;
$$

where

$$
\begin{gathered}
5=2^{3=2} \frac{\mathrm{~K}_{1} \mathrm{~V}}{\sim S}{ }^{3=2}{ }^{\mathrm{h}} 1 \quad \overline{2}+4 \overline{\mathrm{~K}}_{2}+6 \overline{\mathrm{~K}}_{3} \overline{\mathrm{~K}}_{3}^{0}+18 \overline{\mathrm{~K}}_{3}^{0}: \\
\text { В } \cdot=2<\text { н }_{\mathrm{i}}:
\end{gathered}
$$

For this case, the e ective $m$ ass $m$ and the e ective potential ( ) are
and

$$
\begin{aligned}
& 2
\end{aligned}
$$

$$
\begin{aligned}
& { }_{2} \mathrm{P}_{\overline{6}} \text { : }
\end{aligned}
$$

The im aginary part of the metastable excited levels is $\sim \operatorname{Im} E_{n}=\frac{q_{6}^{n}}{n!}\left(\sim \operatorname{Im} E_{0}\right)$, and the im aginary part of the ground state is
where the W KB exponent is
and

The nal result of the decay rate at a nite temperature $T$ is (T) = $2 \mathrm{Im} \mathrm{E}_{0} 1 \mathrm{e}^{\sim}{ }^{6} \exp \mathrm{q}_{6} \mathrm{e}^{\sim}{ }^{6}$, where

$$
\begin{aligned}
& +2 \overline{\mathrm{~K}}_{3} \overline{\mathrm{~K}}_{3}^{0} \frac{710 \text { jot }_{\text {H }} \mathrm{J}^{2=3}}{1+\text { jot }_{\mathrm{H}} \mathrm{~J}^{2=3}}+18 \overline{\mathrm{~K}}_{3}^{0} \frac{1}{1+\text { jot }_{\text {H }} \mathrm{J}^{2=3}}{ }^{7}:
\end{aligned}
$$

The second-order phase transition tem perature characterizing the crossover from quantum to them al regim es is found to be

$$
\begin{aligned}
& +2 \overline{\mathrm{~K}}_{3} \overline{\mathrm{~K}}_{3}^{0} \frac{710 \text { jot }_{\text {H }} \mathrm{J}^{2=3}}{1+\text { jot }_{\mathrm{H}} \mathrm{~J}^{2=3}}+18 \overline{\mathrm{~K}}_{3}^{0} \frac{1}{1+\text { jot }_{\text {H }} \mathrm{J}^{2=3}}{ }^{7}:
\end{aligned}
$$

## VI. CONCLUSIONS

In sum $m$ ary, we have theoretically investigated the quantum tunneling of the $m$ agnetization vector between excited levels in single-dom ain FM nanoparticles in the presence of an extemal magnetic eld at arbitrary angle. W e consider the FM particles w the general structure of $m$ agnetocrystalline anisotropy. By calculating the nonvacuum instanton in the spin-coherent-state path-integral representation, we obtain the analytic form ulas for the tunnel splitting between degenerate excited levels and the im aginary parts of the $m$ etastable excited levels in the low barrier lim it for the extemalm agnetic eld penpendicular to the easy axis ( $\mathrm{H}^{=}=2$ ), and for the eld at an angle between the easy and hard axes $(=2<$ н $<$ ). The tem perature dependences of the decay rates are clearly show $n$ for each case. The low -energy lim it of our results agrees well w ith that of ground-state spin tunneling. O ne im portant conclusion is that the tunneling rate and the tunnel splitting at excited levels depend on the orientation of the extemal magnetic eld distinctly. Even a sm allm isalignm ent of the eld $w$ th $H_{H}=2$ orientation can com pletely change the results of the tunneling rates. A nother interesting conclusion concems the eld strength dependence of the W KB exponent in the tunnel splitting or the tunneling rate. It is found that in a wide range of angles, the $=1 \quad \overline{\mathrm{H}}=\overline{\mathrm{H}}_{\mathrm{C}}$ dependence of the W KB exponent is given by ${ }^{5=4}$ (se Eq. (37b)), not ${ }^{3=2}$ for ${ }_{H}==2$ (sø Eq. (21b)). A s a result, we conclude that both the orientation and the strength of the extemalm agnetic eld are the controllable param eters for the experim ental test of the phenom ena ofquantum tunneling and coherence of the $m$ agnetization vector between excited levels in single-dom ain FM nanoparticles at su ciently low tem peratures. If the experim ent is to be perform ed, there are three control
param eters for com parison w th theory: the angle of the extemalmagnetic eld ${ }_{\mathrm{H}}$, the strength of the eld in term sof , and the tem perature T. Furtherm ore, the ${ }_{\mathrm{H}}$ dependence of the crossover tem perature $T_{c}$ and the angle corresponding to the $m$ axim al value of $T_{c}$ are expected to be observed in further experim ents.

In order to avoid the com plications due to distributions of particle size and shape, som e groups have tried to study the tem perature and eld dependence ofm agnetization reversal of individual $m$ agnets. Recently, $W$ emsdorfer and 00 -w onkers have perform ed the $s w i t c h-$ ing eld $m$ easurem ents on individual ferrim agnetic and insulating $B a F e C$ oT io nanoparticles containing about $10^{5}-10^{6}$ spins at very low tem peratures ( $0.1-6 \mathrm{~K}$ ) ) i They found that above 0.4 K , the m agnetization reversal of these particles is unam biguously described by the N eelB row n theory of them al activated rotation of the particle's m om ent over a well de ned anisotropy energy barrier. Below 0.4K, strong deviations from this model are evidenced which are quantitatively in agreem ent w th the predictions of the M Q T theory without dissipation $\frac{\mid \overline{4} \overline{1} 1}{1} \mathrm{~T}$ he BaFeC oT io nanoparticles have a strong uniaxial m agnetocrystalline anisotropy ${ }^{\text {Pi }}$ [ H ow ever, the theoretical results presented here $m$ ay be useful for checking the general theory in a wide range of system $s$, w ith $m$ ore general $m$ agnetic anisotropy. The experim entalprocedures on single-dom ain FM nanoparticles ofB arium ferrite $w$ ith uniaxial sym $m$ etry $y^{-1} m$ ay be applied to the system $s w$ th $m$ ore general sym $m$ etries. $N$ ote that the inverse of the $W K B$ exponent $B^{1}$ is the $m$ agnetic viscosity $S$ at the quantum -tunnelingdom inated regim e $T \quad T_{C}$ studied by $m$ agnetic relaxation $m$ easurem ents ${ }^{\overline{1}} \mathrm{~T} T$ herefore, the quantum tunneling of the $m$ agnetization should be checked at any н by magnetic relaxation $m$ easurem ents. $O$ ver the past years a lot of experim ental and theoretical w orks were
 lective spin state $S=10$ (in this paper $S=10^{3} \quad 1 \delta^{\delta}$ ). These m easurem ents on m olecular clusters w th $S=10$ suggest that quantum phenom ena $m$ ight be observed at larger system sizes with $S$ 1. Further experim ents should focus on the level quantization of collective spin states of $S=10^{2}-10^{4}$.

T he theoretical calculations perform ed in this paper can be extended to the A FM parti-
cles, where the relevant quantity is the excess spin due to the sm all noncom pensation of tw o sublattices. W ork along this line is still in progress. W e hope that the theoretical results presented in this paper $m$ ay stim ulate $m$ ore experim ents whose aim is observing quantum tunneling and quantum coherence in nanom eter-scale ferrom agnets.

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Figure C aptions:

Fig. 1 The $(=\quad 0)$ dependence of the e ective potential $\bar{E}_{1}()$ for ${ }_{H}=\quad=2(\mathrm{MQC})$. Fig. 2 The ( $=\quad$ ) dependence of the ective potential $\bar{E}_{1}\left(\right.$ ) for ${ }_{\mathrm{H}}=3=4(\mathrm{MQT})$. Here, $\bar{K}_{2}=0: 001$.

F ig. 3 T he tem perature dependence of the relative decay rate $(\mathrm{T})=(\mathrm{T}=0 \mathrm{~K})$ for FM particles in a magnetic eld with a range of angles $=2<\mu<$. Here, $S=6000$, $=1 \quad \overline{\mathrm{H}} \overline{=}_{\mathrm{C}}=0: 01 ; \overline{\mathrm{K}}_{2}=0: 01$, and ${ }_{\mathrm{H}}=3=4$.

Fig. 4 The ${ }_{\boldsymbol{H}}$ dependence of the crossover tem perature $T_{\text {C }}$ for $=2<{ }_{H}<$.






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